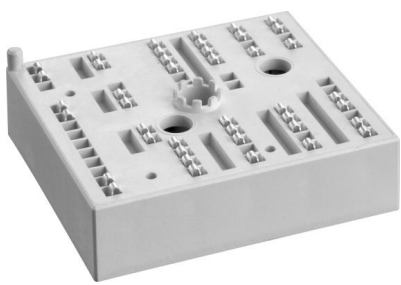


SKiiP 23NAB126V20



MiniSKiiP[®]2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 23NAB126V20

Preliminary Data

Features

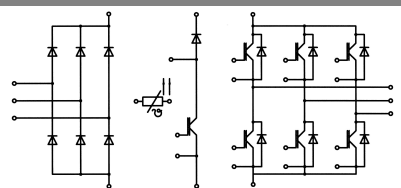
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 16 kVA
- Typical motor power 7 kW

Remarks

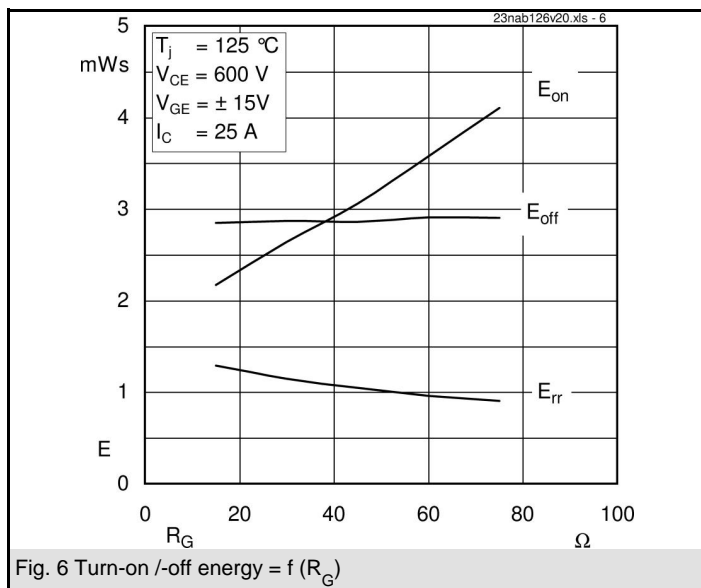
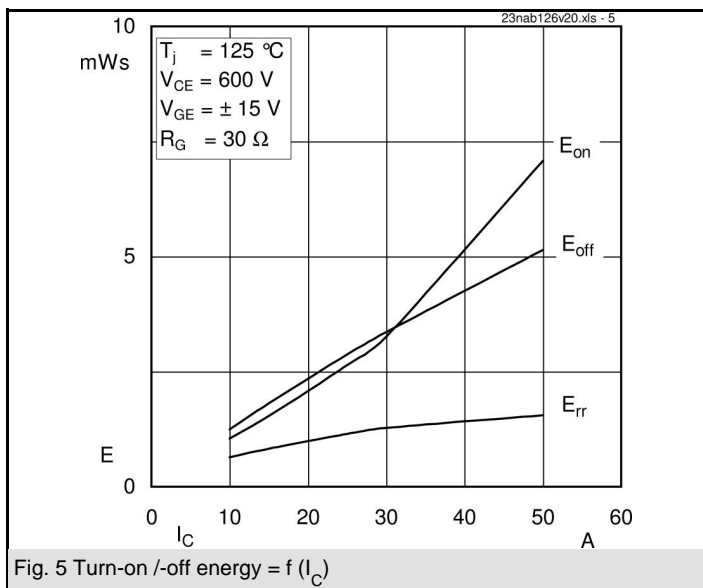
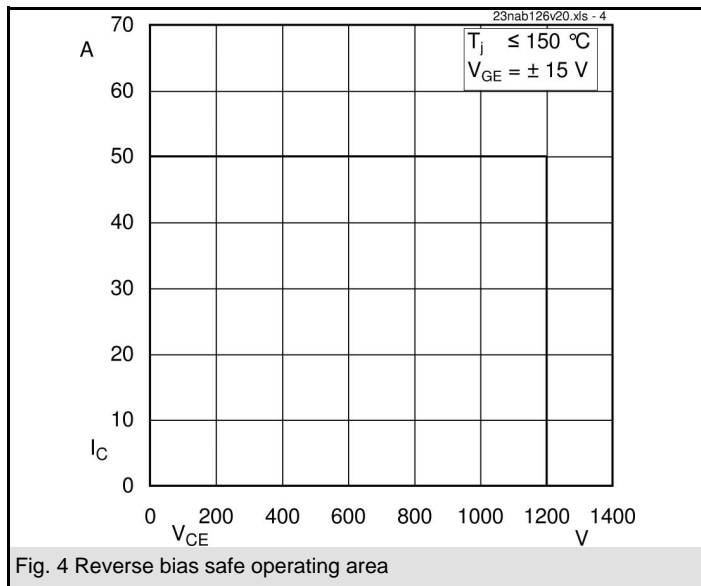
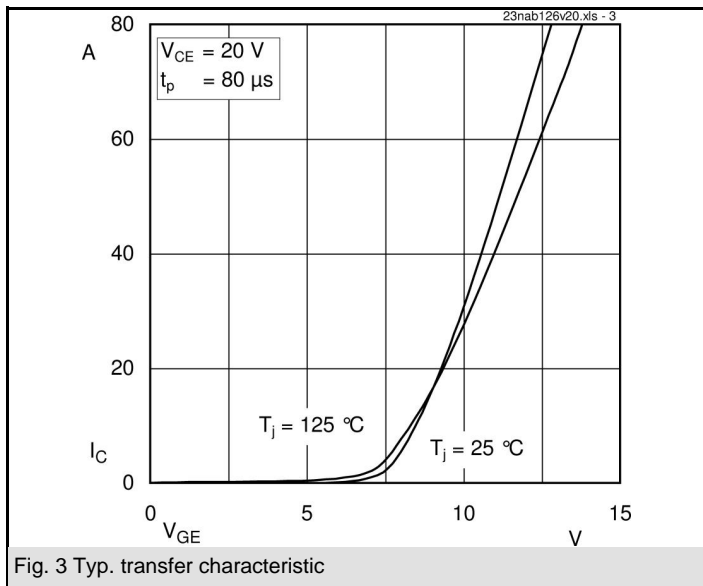
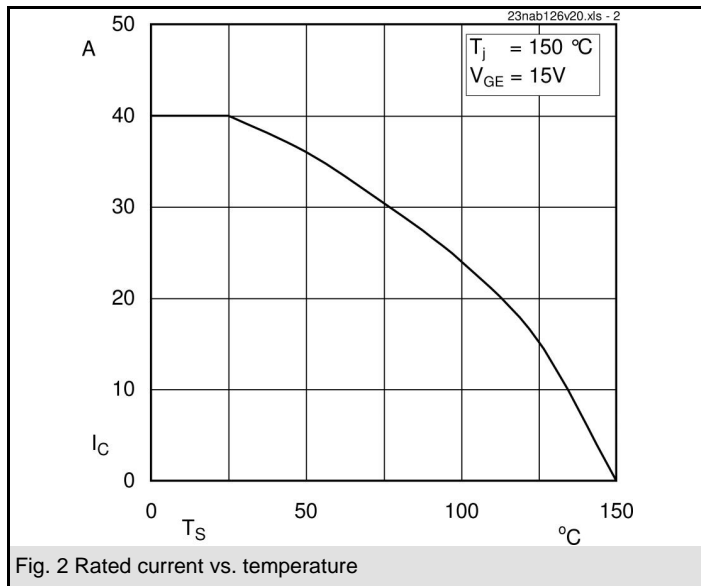
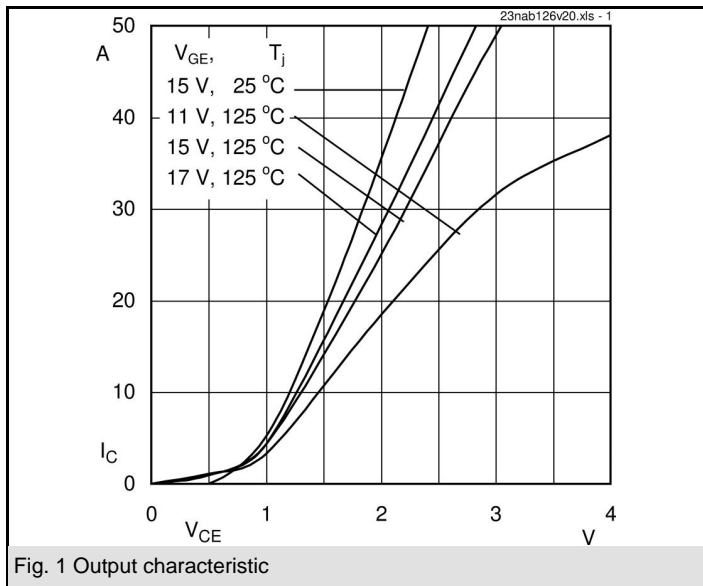
- V_{CEsat} , V_F = chip level value



NAB

| Absolute Maximum Ratings | | $T_S = 25^\circ\text{C}$, unless otherwise specified | | |
|----------------------------------|------------------------------------|---|------------------|----------------------|
| Symbol | Conditions | Values | Units | |
| IGBT - Inverter, Chopper | | | | |
| V_{CES} | $T_S = 25 (70)^\circ\text{C}$ | 1200 | V | |
| I_C | | 41 (31) | A | |
| I_{CRM} | | 50 | A | |
| V_{GES} | | ± 20 | V | |
| T_j | | -40...+150 | $^\circ\text{C}$ | |
| Diode - Inverter, Chopper | | | | |
| I_F | $T_S = 25 (70)^\circ\text{C}$ | 27 (21) | A | |
| I_{FRM} | | 50 | A | |
| T_j | | -40...+150 | $^\circ\text{C}$ | |
| Diode - Rectifier | | | | |
| V_{RRM} | $T_S = 70^\circ\text{C}$ | 1600 | V | |
| I_F | | 46 | A | |
| I_{FSM} | | $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ | 370 | A |
| i^2t | | $t_p = 10 \text{ ms, sin } 180^\circ, T_j = 25^\circ\text{C}$ | 680 | A^2s |
| T_j | | -40...+150 | $^\circ\text{C}$ | |
| Module | | | | |
| I_{RMS} | per power terminal (20 A / spring) | 40 | A | |
| T_{stg} | | -40...+125 | $^\circ\text{C}$ | |
| V_{isol} | AC, 1 min. | 2500 | V | |

| Characteristics | | $T_S = 25^\circ\text{C}$, unless otherwise specified | | | |
|----------------------------------|--|---|------------|-----------|------------------|
| Symbol | Conditions | min. | typ. | max. | Units |
| IGBT - Inverter, Chopper | | | | | |
| V_{CEsat} | $I_{Cnom} = 25 \text{ A}, T_j = 25 (125)^\circ\text{C}$ | | 1,7 (2) | 2,1 (2,4) | V |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 1 \text{ mA}$ | 5 | 5,8 | 6,5 | V |
| $V_{CE(TO)}$ | $T_j = 25 (125)^\circ\text{C}$ | | 1 (0,9) | 1,2 (1,1) | V |
| r_T | $T_j = 25 (125)^\circ\text{C}$ | | 28 (44) | 36 (52) | $\text{m}\Omega$ |
| C_{ies} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 1,8 | | nF |
| C_{oes} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 0,3 | | nF |
| C_{res} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | | 0,2 | | nF |
| $R_{th(j-s)}$ | per IGBT | | 0,9 | | K/W |
| $t_{d(on)}$ | under following conditions | | 75 | | ns |
| t_r | $V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$ | | 30 | | ns |
| $t_{d(off)}$ | $I_{Cnom} = 25 \text{ A}, T_j = 125^\circ\text{C}$ | | 460 | | ns |
| t_f | $R_{Gon} = R_{Goff} = 30 \Omega$ | | 90 | | ns |
| E_{on} | inductive load | | 2,7 | | mJ |
| E_{off} | | | 2,9 | | mJ |
| Diode - Inverter, Chopper | | | | | |
| $V_F = V_{EC}$ | $I_{Fnom} = 25 \text{ A}, T_j = 25 (125)^\circ\text{C}$ | | 2,4 (2,2) | 2,9 (2,7) | V |
| $V_{(TO)}$ | $T_j = 25 (125)^\circ\text{C}$ | | 0,9 (0,6) | 1,1 (0,8) | V |
| r_T | $T_j = 25 (125)^\circ\text{C}$ | | 60 (64) | 72 (76) | $\text{m}\Omega$ |
| $R_{th(j-s)}$ | per diode | | 1,5 | | K/W |
| I_{RRM} | under following conditions | | 30,2 | | A |
| Q_{rr} | $I_{Fnom} = 25 \text{ A}, V_R = 600 \text{ V}$ | | 3,1 | | μC |
| E_{rr} | $V_{GE} = 0 \text{ V}, T_j = 125^\circ\text{C}$ | | 1,2 | | mJ |
| | $di_F/dt = 1200 \text{ A}/\mu\text{s}$ | | | | |
| Diode - Rectifier | | | | | |
| V_F | $I_{Fnom} = 25 \text{ A}, T_j = 25^\circ\text{C}$ | | 1,1 | | V |
| $V_{(TO)}$ | $T_j = 150^\circ\text{C}$ | | 0,8 | | V |
| r_T | $T_j = 150^\circ\text{C}$ | | 13 | | $\text{m}\Omega$ |
| $R_{th(j-s)}$ | per diode | | 1,25 | | K/W |
| Temperature Sensor | | | | | |
| R_{ts} | 3 %, $T_r = 25 (100)^\circ\text{C}$ | | 1000(1670) | | Ω |
| Mechanical Data | | | | | |
| w | | | 65 | | g |
| M_s | Mounting torque | | 2 | 2,5 | Nm |



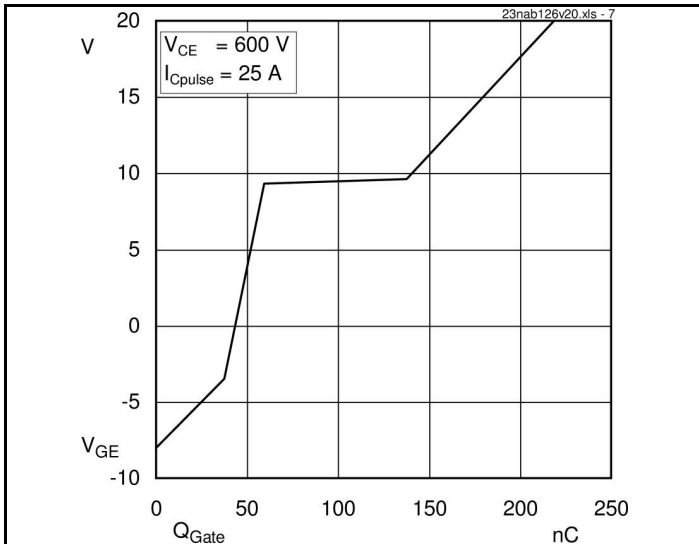


Fig. 7 Typ. Gate charge characteristic

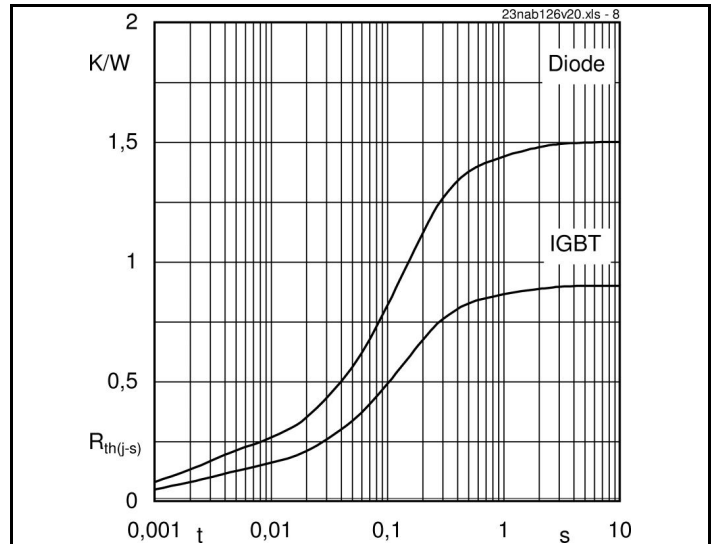


Fig. 8 Thermal impedance

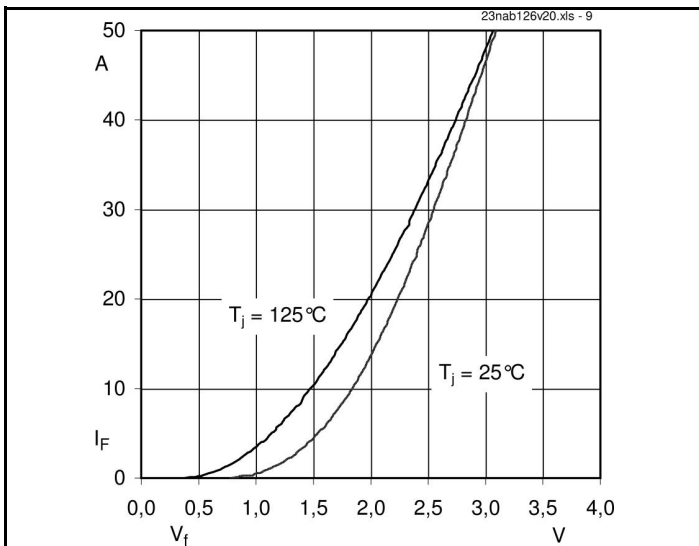


Fig. 9 Freewheeling diode forward characteristic

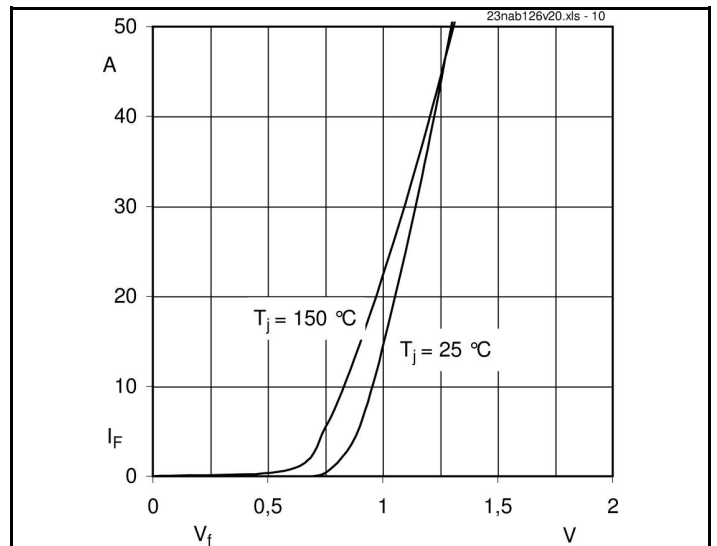
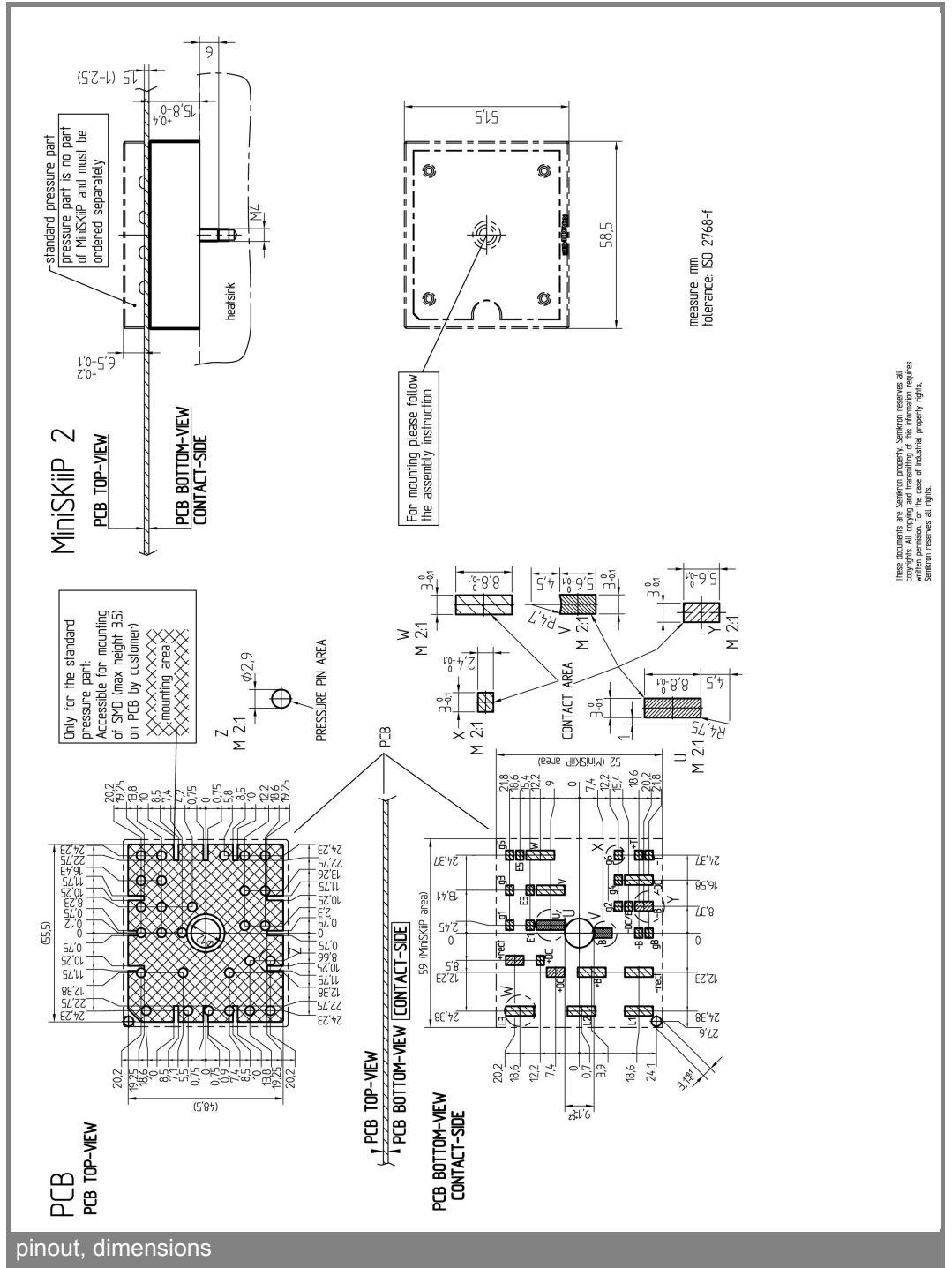
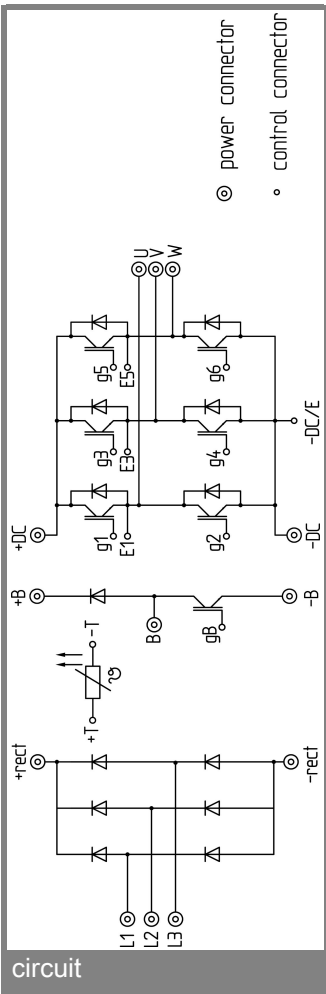


Fig. 10 Typ. input bridge forward characteristic



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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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